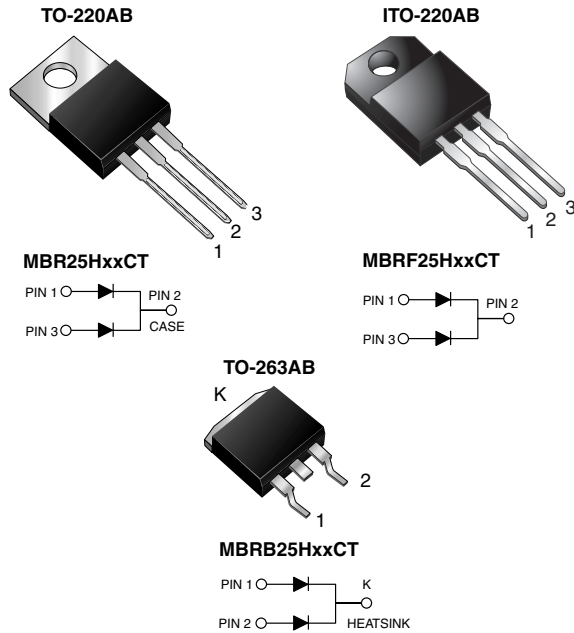




Dual Common-Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC-Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	35 V to 60 V
I_{FSM}	150 A
V_F	0.54 V, 0.60 V
I_R	100 μ A
T_J max.	175 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR25H35CT	MBR25H45CT	MBR25H50CT	MBR25H60CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	V
Working peak reverse voltage	V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V
Max. average forward rectified current (fig. 1)	$I_{F(AV)}$	total device				A
		per diode				
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, $L = 10$ mH	E_{AS}	80				mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150				A
Peak repetitive reverse surge current per diode at $t_p = 2.0$ μ s, 1 kHz	I_{RRM}	1.0		0.5		A
Peak non-repetitive reverse energy (8/20 μ s waveform)	E_{RSM}	25		20		mJ

MBR(F,B)25H35CT thru MBR(F,B)25H60CT



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MAXIMUM RATINGS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MBR25H35CT	MBR25H45CT	MBR25H50CT	MBR25H60CT	UNIT
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 k Ω	V_C	25				kV
Voltage rate of change (rated V_R)	dV/dt	10 000				V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 175				$^\circ\text{C}$
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V_{AC}	1500				V

ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR25H35CT MBR25H45CT		MBR25H50CT MBR25H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	$I_F = 15\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	-	0.64	-	0.70	V
		$T_J = 125\text{ }^\circ\text{C}$		0.50	0.54	0.56	0.60	
	$I_F = 30\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$		-	0.74	-	0.85	
		$T_J = 125\text{ }^\circ\text{C}$		0.63	0.67	0.68	0.72	
Maximum reverse current at rated V_R per diode		$T_J = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	-	100	-	100	μA
		$T_J = 125\text{ }^\circ\text{C}$		6.0	20	4.0	20	mA

Notes

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Thermal resistance, junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	$^\circ\text{C/W}$	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR25H45CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF25H45CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB25H45CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB25H45CT-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	MBR25H45CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	MBRF25H45CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube
TO-263AB	MBRB25H45CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	MBRB25H45CTHE3/81 ⁽¹⁾	1.35	81	800/reel	Tape and reel

Note

(1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

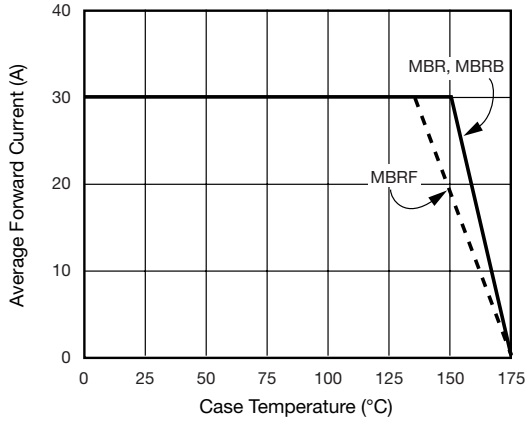


Fig. 1 - Forward Derating Curve (Total)

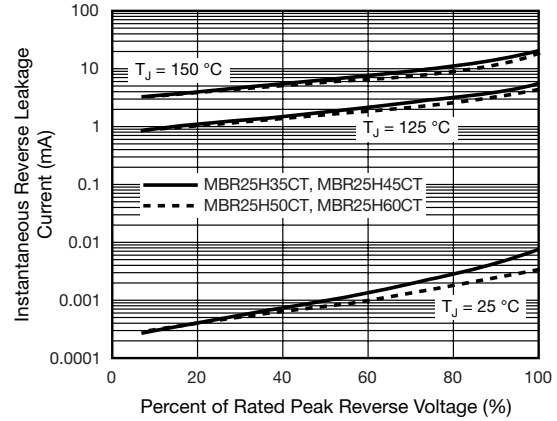


Fig. 4 - Typical Reverse Characteristics Per Diode

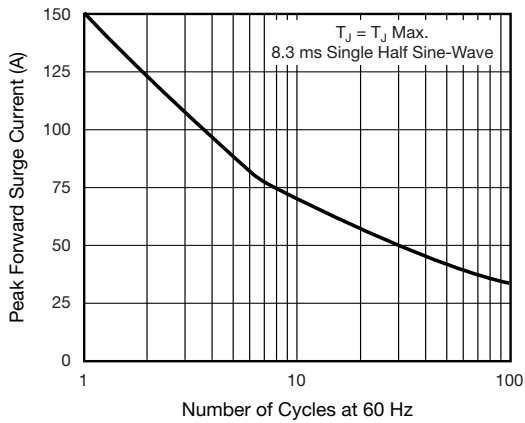


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

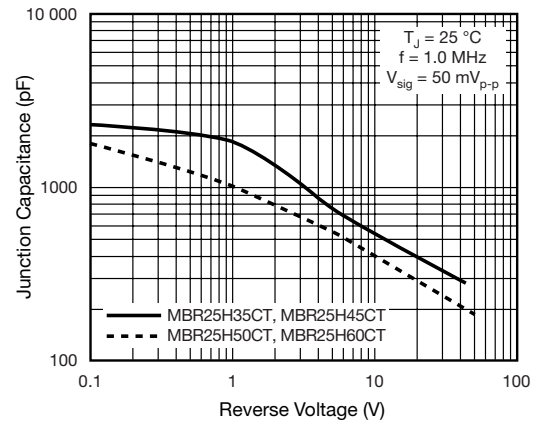


Fig. 5 - Typical Junction Capacitance Per Diode

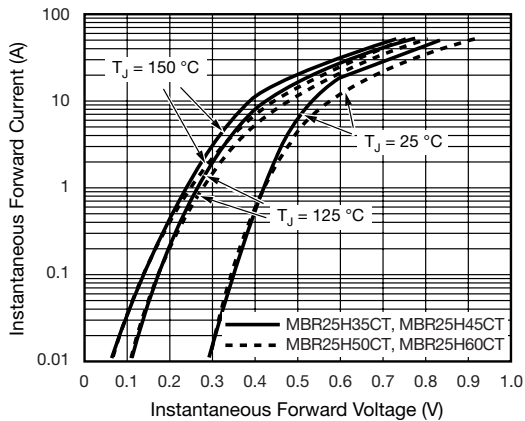


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

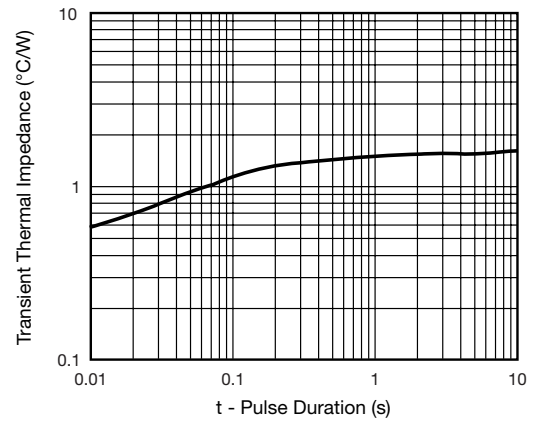


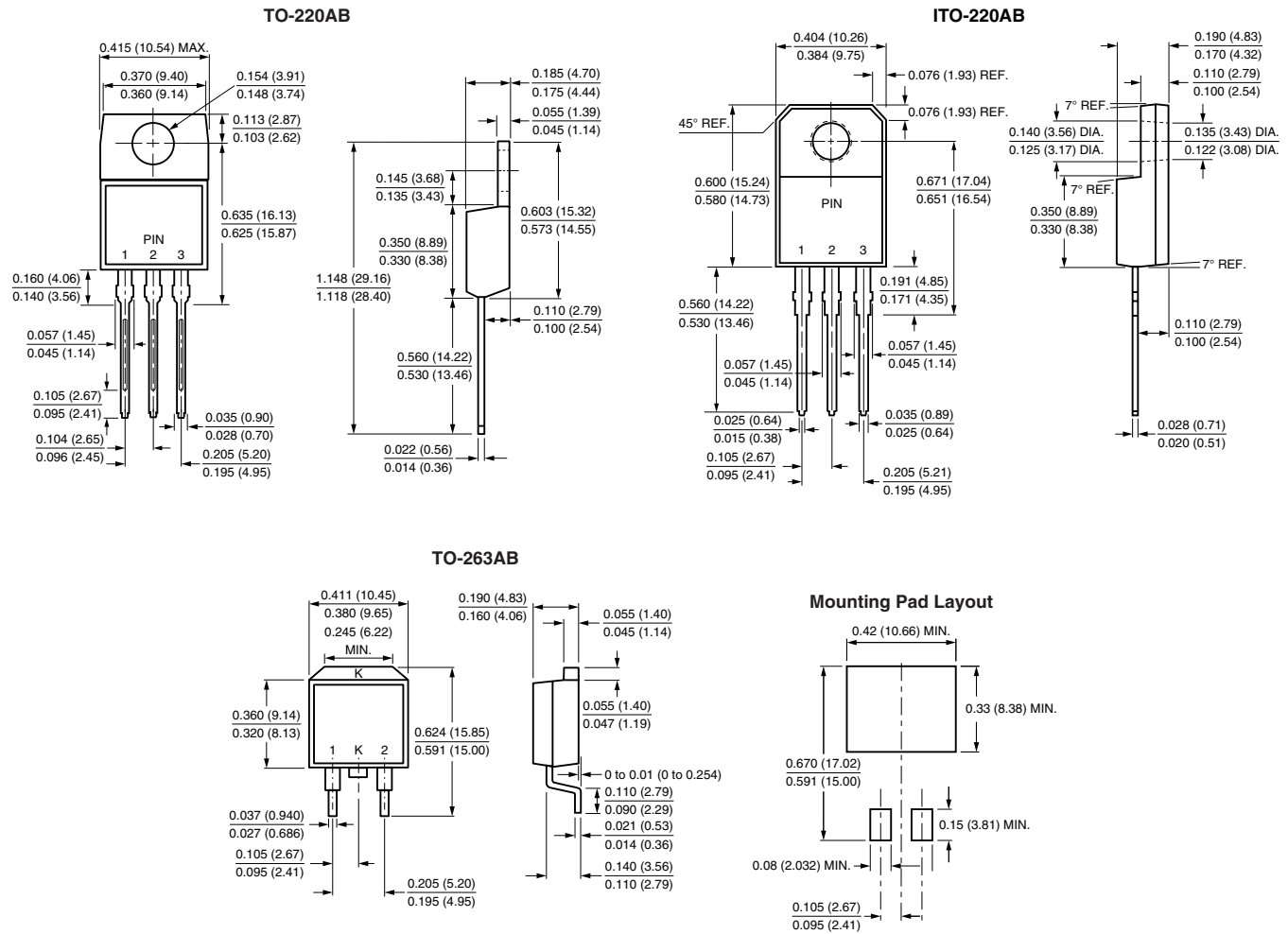
Fig. 6 - Typical Transient Thermal Impedance Per Diode

MBR(F,B)25H35CT thru MBR(F,B)25H60CT



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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